NSN 5961-01-045-8238

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-045-8238

Inclosure Material:

Plastic

Overall Length:

0.643 inches

Overall Height:

0.135 inches

Overall Width:

0.505 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-base, emitter open and 5.0 emitter to base voltage, static, collector open and 60.0 breakdown voltage, collector-to-emitter, base open

Current Rating Per Characteristic:

3.00 amperes source cutoff current and 1.00 amperes source cutoff current

Power Rating Per Characteristic:

60.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Terminal Type And Quantity:

3 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0